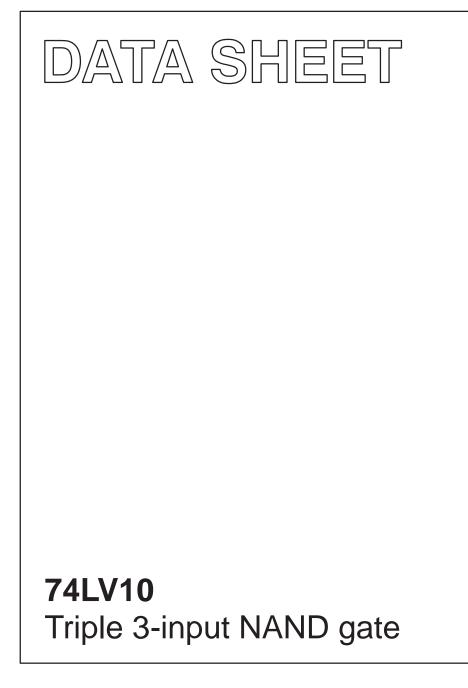
# INTEGRATED CIRCUITS



Product data Supersedes data of 1998 Apr 20 2003 Mar 04



## 74LV10

#### **FEATURES**

- Optimized for Low Voltage applications: 1.0 V to 3.6 V
- Accepts TTL input levels between V<sub>CC</sub> = 2.7 V and V<sub>CC</sub> = 3.6 V
- Typical V<sub>OLP</sub> (output ground bounce) < 0.8 V at V<sub>CC</sub> = 3.3 V,  $T_{amb} = 25 \ ^{\circ}C.$
- Typical V<sub>OHV</sub> (output V<sub>OH</sub> undershoot) > 2 V at V<sub>CC</sub> = 3.3 V, T<sub>amb</sub> = 25 °C.
- Output capability: standard
- I<sub>CC</sub> category: SSI

## QUICK REFERENCE DATA

GND = 0 V;  $T_{amb}$  = 25 °C;  $t_r$  =  $t_f \le 2.5$  ns

#### DESCRIPTION

The 74LV10 is a low-voltage Si-gate CMOS device and is pin and function compatible with 74HC/HCT10.

The 74LV10 provides the 3-input NAND function.

SYMBOL	PARAMETER	CONDITIONS	TYPICAL	UNIT
t <sub>PHL</sub> /t <sub>PLH</sub>	Propagation delay nA, nB, nC to nY	C <sub>L</sub> = 15 pF; V <sub>CC</sub> = 3.3 V	9	ns
Cl	Input capacitance		3.5	pF
C <sub>PD</sub>	Power dissipation capacitance per gate	See Notes 1 and 2	12	pF

NOTES:

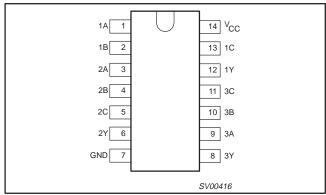
1.  $C_{PD}$  is used to determine the dynamic power dissipation ( $P_D$  in  $\mu W$ )  $P_{D} = C_{PD} \times V_{CC}^{2} \times f_{i} \times N + \Sigma (C_{L} \times V_{CC}^{2} \times f_{o})$  where: N = number of outputs switching;  $f_i$  = input frequency in MHz;  $C_L$  = output load capacitance in pF;  $f_0$  = output frequency in MHz;  $V_{CC}$  = supply voltage in V;

 $\Sigma$  (C<sub>L</sub> × V<sub>CC</sub><sup>2</sup> × f<sub>o</sub>) = sum of the outputs. 2. The condition is V<sub>I</sub> = GND to V<sub>CC</sub>

### ORDERING INFORMATION

PACKAGES	TEMPERATURE RANGE	ORDER CODE	PKG. DWG. #
14-Pin Plastic SO	–40 °C to +125 °C	74LV10D	SOT108-1

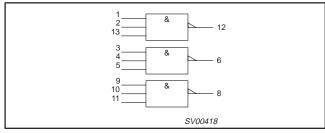
#### **PIN CONFIGURATION**



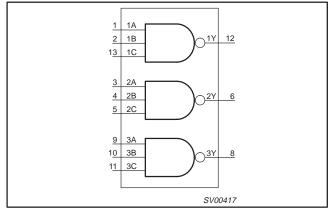
#### **PIN DESCRIPTION**

PIN NUMBER	SYMBOL	NAME AND FUNCTION
1, 3, 9	1A – 3A	Data inputs
2, 4, 10	1B – 3B	Data inputs
7	GND	Ground (0 V)
12, 6, 8	1Y – 3Y	Data outputs
13, 5, 11	1C – 3C	Data inputs
14	V <sub>CC</sub>	Positive supply voltage

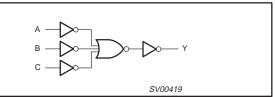
## LOGIC SYMBOL (IEEE/IEC)



## LOGIC SYMBOL



## LOGIC DIAGRAM (ONE GATE)



#### **FUNCTION TABLE**

	INPUTS						
nA	nB	nC	nY				
L	L	L	Н				
L	L	Н	н				
L	Н	L	Н				
L	Н	н	н				
Н	L	L	Н				
Н	L	Н	Н				
Н	Н	L	Н				
Н	Н	Н	L				

NOTES:

H = HIGH voltage level L = LOW voltage level

#### **RECOMMENDED OPERATING CONDITIONS**

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT
V <sub>CC</sub>	DC supply voltage	See Note1	1.0	3.3	3.6	V
VI	Input voltage		0	-	V <sub>CC</sub>	V
V <sub>O</sub>	Output voltage		0	-	V <sub>CC</sub>	V
T <sub>amb</sub>	Operating ambient temperature range in free air	See DC and AC characteristics	-40 -40		+85 +125	°C
		$V_{CC}$ = 1.0 V to 2.0 V	-	-	500	ns/V
t <sub>r</sub> , t <sub>f</sub>	Input rise and fall times	$V_{CC}$ = 2.0 V to 2.7 V	-	-	200	ns/V
		$V_{CC}$ = 2.7 V to 3.6 V	-	-	100	ns/V

NOTE:

1. The LV is guaranteed to function down to  $V_{CC}$  = 1.0 V (input levels GND or  $V_{CC}$ ); DC characteristics are guaranteed from  $V_{CC}$  = 1.2 V to  $V_{CC}$  = 3.6 V.

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#### ABSOLUTE MAXIMUM RATINGS<sup>1, 2</sup>

In accordance with the Absolute Maximum Rating System (IEC 134). Voltages are referenced to GND (ground = 0 V).

SYMBOL	PARAMETER	CONDITIONS	RATING	UNIT
V <sub>CC</sub>	DC supply voltage		-0.5 to +4.6	V
±Ι <sub>ΙΚ</sub>	DC input diode current	$V_{\rm I} < -0.5$ V or $V_{\rm I} > V_{\rm CC} + 0.5$ V	20	mA
±Ι <sub>ΟΚ</sub>	DC output diode current	$V_{O} < -0.5$ V or $V_{O} > V_{CC} + 0.5$ V	50	mA
±ΙΟ	DC output source or sink current (standard outputs)	$-0.5 \text{ V} < \text{V}_{\text{O}} < \text{V}_{\text{CC}} + 0.5 \text{ V}$	25	mA
±I <sub>GND</sub> , ±I <sub>CC</sub>	DC $V_{CC}$ or GND current for types with standard outputs		50	mA
T <sub>stg</sub>	Storage temperature range		-65 to +150	°C
P <sub>TOT</sub>	Power dissipation per package – plastic mini-pack (SO)	for temperature range: -40 °C to +125 °C above +70 °C derate linearly with 8 mW/K	500	mW

NOTES:

1. Stresses beyond those listed may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

2. The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

## DC ELECTRICAL CHARACTERISTICS

Over recommended operating conditions. Voltages are referenced to GND (ground = 0 V).

			LIMITS						
SYMBOL	PARAMETER	TEST CONDITIONS	–40 °C to +85 °C			–40 °C to +125 °C			
			MIN	TYP <sup>1</sup>	MAX	MIN	MAX	1	
		V <sub>CC</sub> = 1.2 V	0.9			0.9			
VIH	HIGH level Input voltage	V <sub>CC</sub> = 2.0 V	1.4			1.4		V	
	, enage	$V_{CC} = 2.7 V \text{ to } 3.6 V$	2.0			2.0			
		V <sub>CC</sub> = 1.2 V			0.3		0.3		
VIL	LOW level Input voltage	V <sub>CC</sub> = 2.0 V			0.6		0.6	V	
	Volkago	V <sub>CC</sub> = 2.7 V to 3.6 V			0.8		0.8	1	
		$V_{CC} = 1.2 \text{ V}; \text{ V}_{I} = \text{V}_{IH} \text{ or } \text{V}_{IL;} - \text{I}_{O} = 100 \mu\text{A}$		1.2					
M	HIGH level output	$V_{CC} = 2.0 \text{ V}; \text{ V}_{I} = \text{V}_{IH} \text{ or } \text{V}_{IL;} - \text{I}_{O} = 100 \mu\text{A}$	1.8	2.0		1.8		v	
V <sub>OH</sub>	voltage; all outputs	$V_{CC} = 2.7 \text{ V}; \text{ V}_{I} = \text{V}_{IH} \text{ or } \text{V}_{IL;} - \text{I}_{O} = 100 \mu\text{A}$	2.5	2.7		2.5			
		$V_{CC} = 3.0 \text{ V}; \text{ V}_{I} = \text{V}_{IH} \text{ or } \text{V}_{IL;} - \text{I}_{O} = 100 \mu\text{A}$	2.8	3.0		2.8			
V <sub>OH</sub>	HIGH level output voltage; STANDARD outputs	$V_{CC} = 3.0 \text{ V}; \text{ V}_{I} = \text{V}_{IH} \text{ or } \text{V}_{IL;} - \text{I}_{O} = 6 \text{ mA}$	2.40	2.82		2.20		V	
		$V_{CC} = 1.2 \text{ V}; \text{ V}_{I} = \text{V}_{IH} \text{ or } \text{V}_{IL}; \text{ I}_{O} = 100 \mu\text{A}$		0		1			
M	LOW level output	$V_{CC} = 2.0 \text{ V}; \text{ V}_{I} = \text{V}_{IH} \text{ or } \text{V}_{IL}; \text{ I}_{O} = 100 \mu\text{A}$		0	0.2		0.2		
V <sub>OL</sub>	voltage; all outputs	$V_{CC}$ = 2.7 V; $V_I$ = $V_{IH}$ or $V_{IL}$ ; $I_O$ = 100 $\mu$ A		0	0.2		0.2	V	
		$V_{CC}$ = 3.0 V; $V_I$ = $V_{IH}$ or $V_{IL}$ ; $I_O$ = 100 $\mu$ A		0	0.2		0.2		
V <sub>OL</sub>	LOW level output voltage; STANDARD outputs	$V_{CC} = 3.0 \text{ V}; \text{ V}_{I} = V_{IH} \text{ or } \text{V}_{IL;} \text{ I}_{O} = 6 \text{ mA}$		0.25	0.40		0.50	V	
I <sub>I</sub>	Input leakage current	$V_{CC} = 3.6 \text{ V}; \text{ V}_{I} = V_{CC} \text{ or GND}$			1.0	1	1.0	μA	
I <sub>CC</sub>	Quiescent supply current; SSI	$V_{CC} = 3.6 \text{ V}; \text{ V}_{I} = V_{CC} \text{ or GND}; \text{ I}_{O} = 0$			20.0		40	μΑ	
$\Delta I_{CC}$	Additional quiescent supply current per input	$V_{CC} = 2.7 \text{ V} \text{ to } 3.6 \text{ V}; \text{ V}_{I} = V_{CC} - 0.6 \text{ V}$			500		850	μΑ	

NOTE:

1. All typical values are measured at  $T_{amb}$  = 25  $^\circ C.$ 

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#### **AC CHARACTERISTICS**

GND = 0 V;  $t_r = t_f \le 2.5$  ns;  $C_L = 50$  pF;  $R_L = 1$  k $\Omega$ 

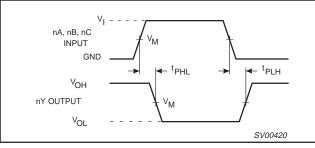
			CONDITION			LIMIT	S					
SYMBOL	PARAMETER	WAVEFORM	-40 °C to +85 °C -40 °C to		–40 °C to +85 °C		+125 °C	UNIT				
	V <sub>CC</sub> (V)		MIN	TYP <sup>1</sup>	MAX	MIN	MAX					
		Figure 4.0	1.2		55							
	Propagation delay				Figure 1 2		2.0		19	36		44
<sup>t</sup> PHL/PLH	<sup>H</sup> nA, nB, nC to nY	Propagation delay nA, nB, nC to nY Figure 1, 2	2.7		14	26		33	ns			
			3.0 to 3.6		10 <sup>2</sup>	21		26				

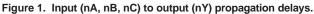
#### NOTES:

1. Unless otherwise stated, all typical values are measured at  $T_{amb} = 25$  °C. 2. Typical values are measured at  $V_{CC} = 3.3$  V.

#### **AC WAVEFORMS**

 $V_M$  = 1.5 V at  $V_{CC} \geq$  2.7 V;  $V_M$  = 0.5  $\times$   $V_{CC}$  at  $V_{CC}$  < 2.7 V;  $V_{\mbox{OL}}$  and  $V_{\mbox{OH}}$  are the typical output voltage drop that occur with the output load.





## **TEST CIRCUIT**

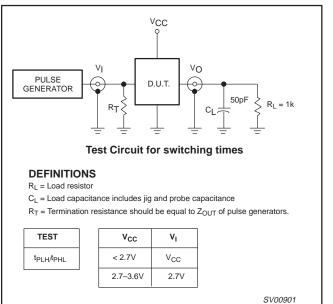
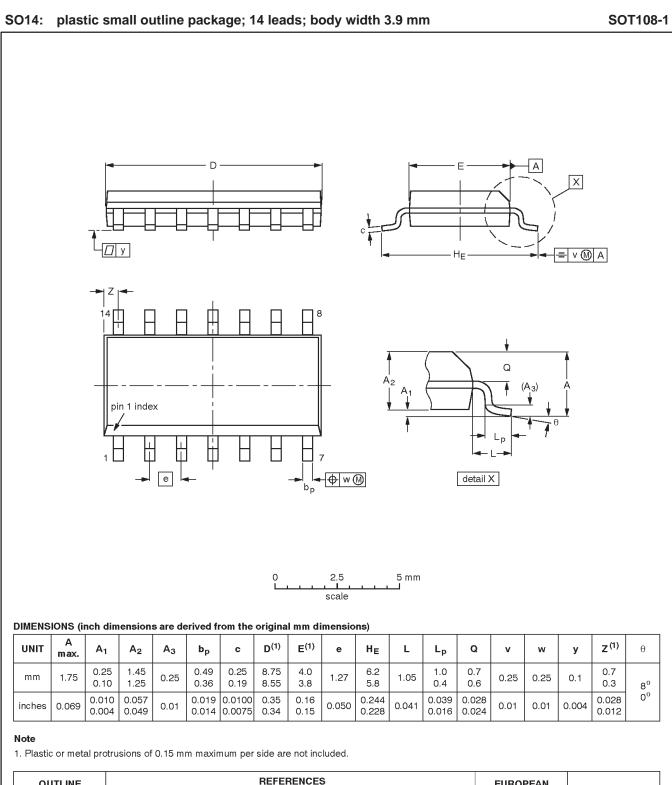


Figure 2. Load circuitry for switching times.

## 74LV10



OUTLINE		REFERENCES				ISSUE DATE
VERSION	IEC	JEDEC	EIAJ		PROJECTION	ISSUE DATE
SOT108-1	076E06	MS-012				<del>-97-05-22</del> 99-12-27

Product data

#### **REVISION HISTORY**

Rev	Date	Description
_3	20030304	Product data (9397 750 11193). ECN 853-1919 29491 of 07 February 2003. Supersedes data of 1998 Apr 20 (9397 750 04407).
		Modifications:
		<ul> <li>Delete DIL, SSOP and TSSOP package ordering and package outlines (discontinued options).</li> </ul>
		Correct power dissipation formula.
_2	19980420	Product specification (9397 750 04407). ECN 853-1919 19256 of 20 April 1998. Supersedes data of 1997 Feb 12.

#### Data sheet status

Level	Data sheet status <sup>[1]</sup>	Product status <sup>[2] [3]</sup>	Definitions
I	Objective data	Development	This data sheet contains data from the objective specification for product development. Philips Semiconductors reserves the right to change the specification in any manner without notice.
	Preliminary data	Qualification	This data sheet contains data from the preliminary specification. Supplementary data will be published at a later date. Philips Semiconductors reserves the right to change the specification without notice, in order to improve the design and supply the best possible product.
111	Product data	Production	This data sheet contains data from the product specification. Philips Semiconductors reserves the right to make changes at any time in order to improve the design, manufacturing and supply. Relevant changes will be communicated via a Customer Product/Process Change Notification (CPCN).

[1] Please consult the most recently issued data sheet before initiating or completing a design.

[2] The product status of the device(s) described in this data sheet may have changed since this data sheet was published. The latest information is available on the Internet at URL http://www.semiconductors.philips.com.

[3] For data sheets describing multiple type numbers, the highest-level product status determines the data sheet status.

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Limiting values definition — Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 60134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

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Date of release: 03-03

9397 750 11193

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